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INFORMATION DISCLOSURE STATEMENT BY APPLICANT *(use as many sheets as necessary)*				Application Number	Not assigned yet
				Filing Date	On even date herewith
				First Named Inventor	K. OSADA, et al.
				Art Unit	Not assigned yet
				Examiner Name	Not assigned yet
Sheet	1	of	1	Attorney Docket Number	500.35578CC5

U.S. PATENT DOCUMENTS

Examiner Initials'	Cite No.[1]	Document Number — Number-Kind Code[2] (if known)		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
HH		5.253.207		10/93	Shikatani	
		5.675.529		10/97	Poole	
		5.574.687		11/96	Nakase	
		5.517.462		05/96	Iwamoto et al	
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Examiner Initials'	Cite No.[1]	Foreign Patent Document — Country Code[3]–Number[4]–Kind Code[5] (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T[6]
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		2-50396	2/90			
HH		7-201197	8/95			

OTHER PRIOR ART—NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No.[1]	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T[2]
HH		Osada et al., "A 2ns Access, 285MHz, Two-Port Cache Macro Using Double Global Bit-Line Pairs" ISSCC Digest of Technical Papers, pp. 402-403	
HH		Kushiyami et al., "A 295MHz CMOS 1M (x256) Embedded SRAM Using Bi-directional Read/Write Shared Sense Amps and Self-Timed Pulsed Word-Line Drivers" ISSCC Digest of Technical Papers, Feb. 1995, pp. 304-305	
HH		IEEE Journal of Solid State Circuits, Vol. 23, No. 5, Oct. 1988, pp. 1048-1053	

Examiner Signature	H. Ho	Date Considered	3/16/04

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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